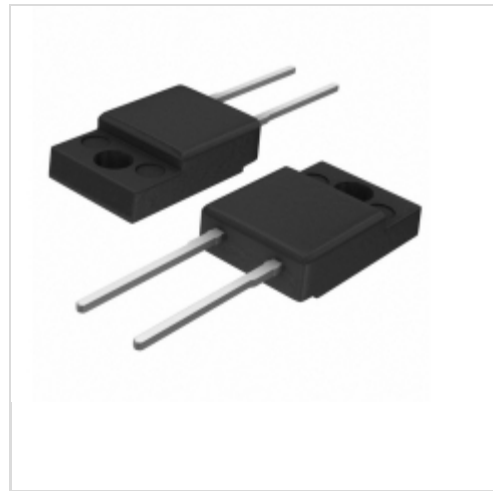


**BYV29F-400-E3/45**



Vishay / Semiconductor - Diodes Division

DIODE GEN PURP 400V 8A ITO220AC

Lead free / RoHS Compliant

Discrete Semiconductor Products

1.BYV29F-400-E3/45.pdf

2.BYV29F-400-E3/45.pdf

Buy Now

**Out Stock**

**0 pcs**

Minimum:1

Multiples:100

Manufacturer lead time 10 weeks

We can supply Vishay / Semiconductor - Diodes Division BYV29F-400-E3/45, use the request quote form to request BYV29F-400-E3/45 price, Vishay / Semiconductor - Diodes Division Datasheet PDF and lead time.Zeanoit.com is a professional electronic components distributor. With 3+ Million line items of available electronic components can ship in short lead-time, over 250 thousand part numbers of electronic components in stock for immediately delivery, which may include part number BYV29F-400-E3/45.The price and lead time for BYV29F-400-E3/45 depending on the quantity required, availability and warehouse location.

Shopping Process

**1**

Confirm the product

**2**

submit the order

**3**

payment

**4**

wait for delivery

**5**

receive the goods

Specifications

Voltage - Forward (Vf) (Max) @ If:	1.25V @ 8A
Voltage - DC Reverse (Vr) (Max):	400V
Supplier Device Package:	ITO-220AC
Speed:	Fast Recovery = 200mA (Io)
Series:	-
Reverse Recovery Time (trr):	50ns
Packaging:	Tube
Package / Case:	TO-220-2 Full Pack, Isolated Tab
Operating Temperature - Junction:	-40°C ~ 150°C
Mounting Type:	Through Hole
Diode Type:	Standard
Current - Reverse Leakage @ Vr:	10µA @ 400V
Current - Average Rectified (Io):	8A
Capacitance @ Vr, F:	-

Related products



**BYV29F-300**  
PHI

RFQ



**BYV29F-300-E3/45**  
DIODE GEN PURP 300V 8A ITO220AC  
Vishay Semiconductor Diodes Division

RFQ



**BYV29B-600**  
NXP

RFQ



**BYV29B-600,118**  
DIODE GEN PURP 600V 9A D2PAK  
WeEn Semiconductors

RFQ



**BYV29F-600**  
NXP

RFQ



**BYV29F-400HE3/45**  
DIODE GEN PURP 400V 8A ITO220AC  
Vishay Semiconductor Diodes Division

RFQ



**BYV29F-300HE3/45**  
DIODE GEN PURP 300V 8A ITO220AC  
Vishay Semiconductor Diodes Division

RFQ



**BYV29F-600,127**  
DIODE GEN PURP 600V 9A TO220AC  
WeEn Semiconductors

RFQ



**BYV29FB-600,118**  
DIODE GEN PURP 600V 9A D2PAK  
WeEn Semiconductors

RFQ



**BYV29F-500**  
NXP

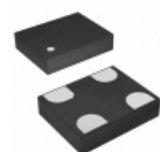
RFQ

Guess You May Looking For



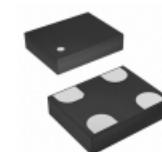
**SIT1602BI-73-33N-3.570000D**  
-40 TO 85C, 2016, 50PPM, 3.3V, 3  
SITIME

RFQ



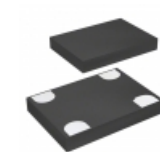
**SIT1602BC-22-30E-28.636300D**  
-20 TO 70C, 3225, 25PPM, 3.0V, 2  
SITIME

RFQ



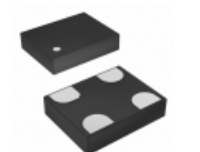
**SIT1602BC-22-30S-48.000000D**  
-20 TO 70C, 3225, 25PPM, 3.0V, 4  
SITIME

RFQ



**SIT1602BC-82-18E-12.000000T**  
-20 TO 70C, 7050, 25PPM, 1.8V, 1  
SITIME

RFQ



**SIT1602BI-21-25E-4.096000D**  
-40 TO 85C, 3225, 20PPM, 2.5V, 4  
SITIME

RFQ



**SIT8008BC-71-18E-27.000000E**  
OSC MEMS 27.0000MHZ LVCMOS SMD  
SITIME

RFQ



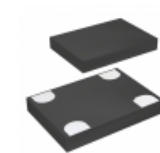
**SIT1602BC-81-XXS-40.500000Y**  
-20 TO 70C, 7050, 20PPM, 2.25V-3  
SITIME

RFQ



**SIT8008BC-22-33E-24.000000E**  
OSC MEMS 24.0000MHZ LVCMOS SMD  
SITIME

RFQ



**SIT1602BI-81-30S-33.000000Y**  
-40 TO 85C, 7050, 20PPM, 3.0V, 3  
SITIME

RFQ



**SIT8009BC-13-18E-125.000000D**  
OSC MEMS 125.0000MHZ LVCMOS SMD  
SITIME

RFQ